

EPO-TEK[®] H20E-PFC **Technical Data Sheet**

> For Reference Only Electrically Conductive, Silver Epoxy

Date: February 2023 Rev: XIV No. of Components: Two Mix Ratio by Weight: 1:1Specific Gravity: Part A: 2.88 Part B: 3.31 Pot Life: 3 Days Shelf Life- Bulk: One year at room temperature Shelf Life- Syringe: One year at -40°C

Recommended Cure: 150°C / 1 Hour

Minimum Alternative Cure(s): May not achieve performance properties listed below 175°C / 45 Seconds 150°C / 5 Minutes 120°C / 15 Minutes

80°C / 3 Hours

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

Product Description: EPO-TEK® H20E-PFC is a two component, semiconductor grade epoxy, designed for flip chip interconnects using a solder-free joining method.

Typical Properties: Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results. Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:				
* Color (before cure):	Part A: Silve	er Pa	rt B: Silver	
* Consistency:	Smooth thix	Smooth thixotropic paste		
* Viscosity (23°C) @ 100 rpm:	3,000) - 4,000	cPs	
Thixotropic Index:		4.8		
* Glass Transition Temp:		≥ 80	°C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)	
Coefficient of Thermal Expansion (CTE):			
Below T	g:	48	x 10 ⁻⁶ in/in°C	
Above T	g:	106	x 10 ⁻⁶ in/in°C	
Shore D Hardness:		50		
Lap Shear @ 23°C:		850	psi	
Die Shear @ 23°C:		≥ 5	Kg 1,778 psi	
Degradation Temp:		407	°C	
Weight Loss:				
@ 200°		0.46	%	
@ 250°		1.02	%	
@ 300°	C:	1.78	%	
Suggested Operating Temperature:		< 325	°C (Intermittent)	
Storage Modulus:		921,254	psi	
Ion Content:	CI-: 1	199 ppm	Na⁺: 12 ppm	
	NH4 ⁺ : 3	349 ppm	K ⁺ : 12 ppm	
* Particle Size:		≤ 20	microns	
ELECTRICAL AND THERMAL PROPERTIES:				
Thermal Conductivity:		3.2	W/mK	
* Volume Resistivity @ 23°C:	<	≤ 0.0004	Ohm-cm	

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EPO-TEK® H20E-PFC Advantages & Suggested Application Notes:

- Stencil printing of small dots or "bumps" the size of 4 mil diameter with 8 mil pitch can be achieved.
- Product may be applied at the wafer level or single-chip bumping of prototypes.
- Final system packaging can be hermetic micro-electronic cases or open-faced circuits using potting resin or housing.
- Low temperature cure capable between 70°C 100°C allows for lower cost plastic substrates / housings to be used.
- Suggested for flip chip packaging applications found in memory devices (SRAM, DRAM), watch modules, RFID tags, smart-cards, military, and medical devices.
- Passes NASA low outgassing standard ASTM E595 with proper cure -<u>http://outgassing.nasa.gov/</u>
- Compatible with Au, Cu, Ag, Ag-Pd component or substrate metallization.
- Recommended to be used with chips or wafers which have UBM layer already deposited.
- Compatible with automated dispensing equipment.